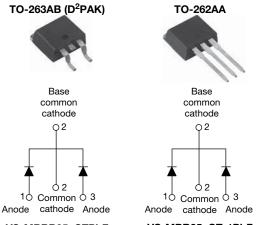
VS-MBRB25..CTPbF, VS-MBR25..CT-1PbF Series

Vishay Semiconductors

## High Performance Schottky Rectifier, 2 x 15 A



VS-MBRB25..CTPbF

VS-MBR25..CT-1PbF

PRODUCT SUMMARY					
Package	TO-263AB (D <sup>2</sup> PAK), TO-262AA				
I <sub>F(AV)</sub>	30 A				
V <sub>R</sub>	35 V, 45 V				
V <sub>F</sub> at I <sub>F</sub>	0.73 V				
I <sub>RM</sub> max.	40 mA at 125 °C				
T <sub>J</sub> max.	150 °C				
Diode variation	Single die				
E <sub>AS</sub>	16 mJ				

#### **FEATURES**

- 150 °C T<sub>J</sub> operation
- Center tap D<sup>2</sup>PAK and TO-262 packages
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
   FREE
- strength and moisture resistance
  Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS A	AJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I <sub>F(AV)</sub>	Rectangular waveform (per device)	30	٨		
I <sub>FRM</sub>	T <sub>C</sub> = 130 °C (per leg)	30	A		
V <sub>RRM</sub>		35, 45	V		
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	1060	А		
V <sub>F</sub>	30 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.73	V		
TJ	Range	-65 to +150	°C		

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-MBRB2535CTPbF VS-MBR2535CT-1PbF	VS-MBRB2545CTPbF VS-MBR2545CT-1PbF	UNITS	
Maximum DC reverse voltage	V <sub>R</sub>	35	45	V	
Maximum working peak reverse voltage	V <sub>RWM</sub>		40	V	

ABSOLUTE MAXIMUM RATIN	IGS				
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS		VALUES	UNITS
Maximum average per leg	1	$T_{\rm C} = 130 ^{\circ}\text{C}$ , rated $V_{\rm B}$		15	
forward current per device	I <sub>F(AV)</sub>	$T_{\rm C} = 150$ C, lated $V_{\rm R}$		30	
Peak repetitive forward current per leg	I <sub>FRM</sub>	Rated V <sub>R</sub> , square wave	, 20 kHz, T <sub>C</sub> = 130 °C	30	
Non-repetitive peak surge current	I <sub>ESM</sub>	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated V <sub>RRM</sub> applied	ated load A vith rated 1060	
		Surge applied at rated single phase, 60 Hz	oad conditions halfwave,	150	
Non-repetitive avalanche energy per leg	E <sub>AS</sub>	$T_J = 25 \ ^{\circ}C, \ I_{AS} = 2 \ A, \ L$	= 8 mH	16	mJ
Repetitive avalanche current per leg	I <sub>AR</sub>	Current decaying linear Frequency limited by T	ly to zero in 1 μs J maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical	2	А

Revision: 17-Jul-14

Document Number: 94308

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## VS-MBRB25..CTPbF, VS-MBR25..CT-1PbF Series

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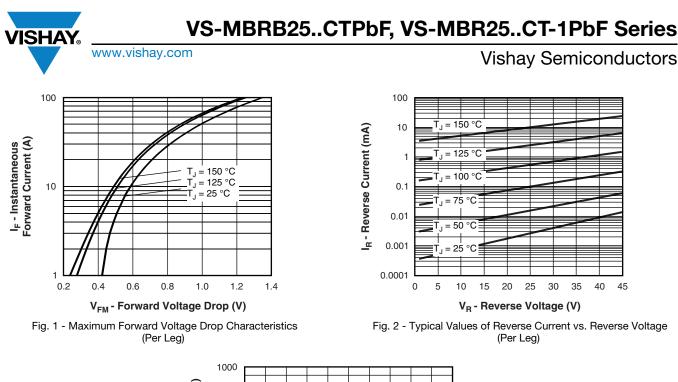
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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
	V <sub>EM</sub> <sup>(1)</sup>	30 A	T <sub>J</sub> = 25 °C	0.82	V
Maximum forward voltage drop	V FM \''	50 A	T <sub>J</sub> = 125 °C	0.73	
Maximum instantaneous	I <sub>BM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	Rated DC voltage 0.2 mA	<b>m</b> (	
reverse current	'RM`'	T <sub>J</sub> = 125 °C	haled DC vollage	40	ША
Threshold voltage	V <sub>F(TO)</sub>	T T maximum		0.355	V
Forward slope resistance	r <sub>t</sub>	$T_J = T_J maximum$		12.3	mΩ
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal range	ge 100 kHz to 1 MHz), 25 °C	700	pF
Typical series inductance	L <sub>S</sub>	Measured from top of terminal to mounting plane		8.0	nH
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs

#### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	OL TEST CONDITIONS		UNITS	
Maximum junction temper	ature range	TJ		-65 to +150	°C	
Maximum storage tempera	ature range	T <sub>Stg</sub>		-65 to +175	°C	
Maximum thermal resistance, junction to case per leg		R <sub>thJC</sub>	DC operation	1.5	°C 444	
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50	°C/W	
Approximate weight				2	g	
Approximate weight				0.07	oz.	
Mounting torque	minimum		Non-lubricated threads	6 (5)	kgf · cm	
maximum			Non-hubilitated trileads	12 (10)	(lbf · in)	
Marking daviaa			Case style D <sup>2</sup> PAK	MBRB2	545CT	
Marking device			Case style TO-262	MBR254	45CT-1	



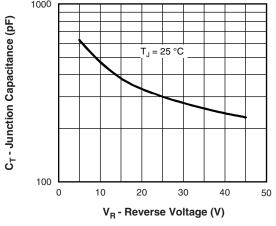


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

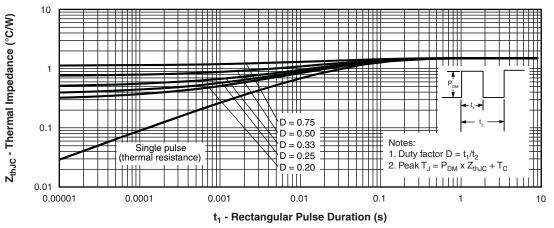
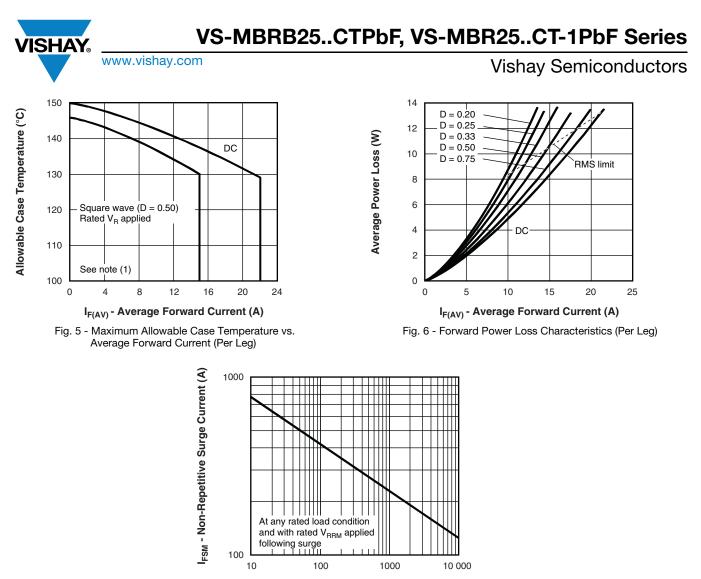


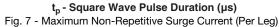
Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

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#### Note

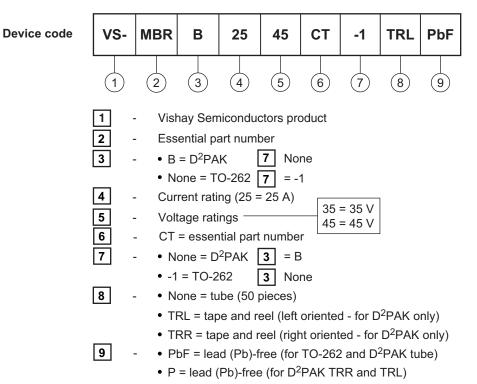
 $<sup>^{(1)}</sup>$  Formula used:  $T_{C} = T_{J} - (Pd + Pd_{REV}) \times R_{thJC};$ Pd = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at ( $I_{F(AV)}/D$ ) (see fig. 6); Pd\_{REV} = Inverse power loss =  $V_{R1} \times I_{R} (1 - D); I_{R}$  at  $V_{R1}$  = Rated  $V_{R}$ 



### VS-MBRB25..CTPbF, VS-MBR25..CT-1PbF Series

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### **ORDERING INFORMATION TABLE**



LINKS TO RELAT	ED DOCUMENTS
Dimensions	www.vishay.com/doc?95014
Part marking information	www.vishay.com/doc?95008
Packaging information	www.vishay.com/doc?95032

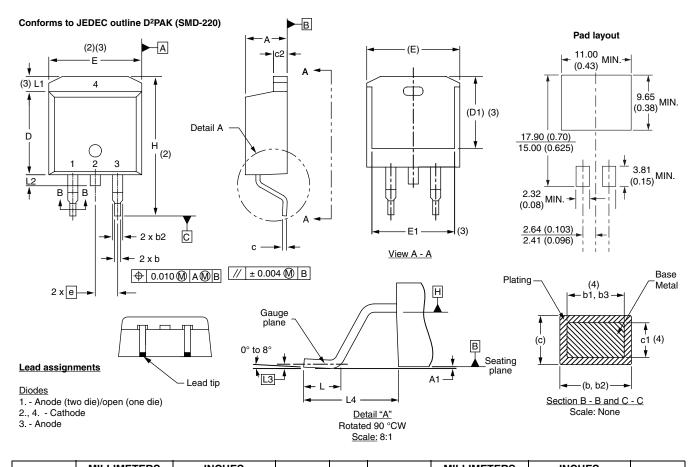
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Vishay High Power Products

## D<sup>2</sup>PAK, TO-262

### DIMENSIONS FOR D<sup>2</sup>PAK in millimeters and inches

SHA



SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
с	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100	BSC	
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

<sup>(7)</sup> Outline conforms to JEDEC outline TO-263AB

#### Notes

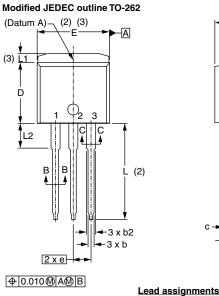
- <sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}\,$  Thermal pad contour optional within dimension E, L1, D1 and E1
- <sup>(4)</sup> Dimension b1 and c1 apply to base metal only
- <sup>(5)</sup> Datum A and B to be determined at datum plane H
- <sup>(6)</sup> Controlling dimension: inch

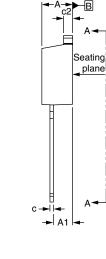
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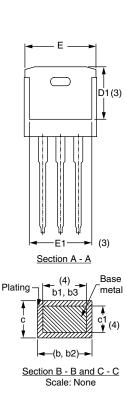
D<sup>2</sup>PAK, TO-262



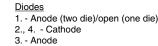
### DIMENSIONS FOR TO-262 in millimeters and inches







Lead tip



	MILLIM	MILLIMETERS		INCHES		
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	2.03	3.02	0.080	0.119		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	
D1	6.86	8.00	0.270	0.315	3	
E	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54	2.54 BSC		BSC		
L	13.46	14.10	0.530	0.555		
L1	-	1.65	-	0.065	3	
L2	3.56	3.71	0.140	0.146		

#### Notes

- <sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- <sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

<sup>(5)</sup> Controlling dimension: inches

<sup>(6)</sup> Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline

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